Generation and Application of Mid-IR Sources

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Generation of Mid-IR Sources

- > 2 micron laser sources
- 2 micron laser pumped Mid-IR sources
- Separation of Mid-IR Sources
- **Outlook**

Generation of Mid-IR Sources



Generation of Mid-IR Sources
2 micron laser sources
2 micron laser pumped Mid-IR sources
Application of Mid-IR Sources
Outlook

- Diode pumped solid state (DPSS) Laser
- Fiber Laser
- Difference frequency generation (DFG)
- Optical parametric oscillator (OPO)
- Semiconductor Laser
- Free Electron Laser



Tm^{3+}/Ho^{3+} doped laser hosts

Table 11 Important data on Ho ³⁺ -goped laser hosts (BYF: BaY ₂ F ₈). Some data are taken from [7, 11, 64, 180, 181]				
Host crystal	YAG	YALO	YLF	BYF
Symmetry	cubic	orthorhombic	tetragonal	monoclinic
⁵ I ₇ levels [cm ⁻¹]	5229, 5232, 5243,	5186, 5187, 5222,	5153, 5157, 5157,	5173, 5177, 5189,
	5250, 5303, 5312,	5253, 5255, 5264,	5164, 5164, 5185,	5191, 5197, 5220,
	5320, 5341, 5352,	5266, 5268, 5280,	5185, 5207, 5229,	5220, 5220, 5220,
	5375, 5395, 5404,	5288, 5318, 5326,	5229, 5233, 5291,	5228, 5256, 5269,
	5418, 5455, 5485	5337, 5346, 5357	5293, 5293, 5293	5273, 5276, 5358
$f_{u,(i)}$	0.105 (1), 0.096 (3)	0.100(0)	0.087 (0)	0.084 (1)
$\tau_{\rm f}$ [ms]	7.8	8.1	16.1	17.9
${}^{5}I_{8}$ levels [cm ⁻¹]	0, 4, 41, 51, 141,	0, 6, 37, 48, 58,	0, 0, 7, 23, 48,	0, 20, 37, 39, 54,
	144, 150, 162, 398, 418,	71, 100, 126, 137, 193,	56, 72, 72, 217, 270,	58, 89, 120, 200, 200,
	448, 457, 498, 506, 520,	211, 222, 289, 327, 425,	276, 276, 283, 290, 303,	239, 276, 310, 324, 352,
	531, 535	474, 499	303, 315	382, 399
$f_{g,(i)}$	0.018 (10), 0.012 (16)	0.012 (15)	0.025 (14)	0.025 (13)
λ _s [nm]	2090, 2121	2122	2062	2060
$\sigma_{\rm e}(\lambda_{\rm s}) \ [10^{-20} \ {\rm cm}^2]$	1.2, 0.55	0.82	$1.9 (E \ c)$	$1.18 (E \ c)$
$rac{\sigma_{\rm e}(\lambda_{\rm s})}{\sigma_{\rm a}(\lambda_{\rm s})}$	5.81, 8.13	8.39	3.44	3.42
$I_{\rm sat}^s$ [kW cm ⁻²]	0.866, 1.94	1.26	0.244	0.353
λ _p [nm]	1907, 2017	1976	1948	1933
$\sigma_{a,p}(\lambda_p) \ [10^{-20} \ cm^2]$	1.2, 0.15	0.9	$1.2 (E \ c)$	$0.7 (E \ c)$
$\frac{\sigma_{e,p}(\lambda_p)}{\sigma_{a,p}(\lambda_p)}$	0.64, 2.53	1.58	0.88	0.74
$I_{\rm sat}^{\rm p}$ [kW cm ⁻²]	0.949, 0.898 (2090 nm) 2.16, 2.04 (2121 nm)	1.35	0.258	0.376
$E_{\rm p}^{\rm max}$ [cm ⁻¹]	700	550	400	415

Energy levels of Tm,Ho codoped YLF



Energy Transfer Upconversion (ETU)

2 micron DPSS laser





✓ The crystal temperature = 293 K
 ✓ Output coupler = 2 %

 \checkmark Pth = 250 mW

 \square The single frequency P_{max}

$$= 113 \text{ mW} (P_{in} = 2810 \text{ mW})$$

✓ The single frequency could be tuned from 2063 to 2069 nm by changing the angle of the 1 mm thick etalon

Chinese Optics Letters, **3**, 463-465 (2005) Optics & Laser Technology, **39**, 782-785 (2007)

2 micron fiber laser - Diode pumped fiber laser



OPTICS EXPRESS Vol. 18, 8937 (2010)

2 micron fiber laser - All-fiber laser



Pump = 20 W RFL @ 1231 nm Output = 7 W @ 1956 nm Slope efficiency = 35 %



Figure 3. Scheme of a thulium-doped fibre laser:

(1) 1058-nm single-mode ytterbium-doped fibre laser; (2) phosphosilicate fibre; (3) thulium-doped fibre; (4) output end of the thulium-doped fibre. The scheme shows splices (circles) and FBGs (HR: highly reflecting FBG; OC: output coupler FBG).



QUANTUM ELECTRONICS Vol. 35, 586 (2005)

Setup of our 2 micron laser







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2 micron laser pumped Mid-IR sources

Optical parametric oscillator (OPO)

Difference frequency generation (DFG)





CHIN. PHYS. LETT. Vol. 26, 024209 (2009)

2 micron laser pumped Mid-IR sources

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Atomic & Molecular

Physics

Mid-IR Sources (2~12 micron)

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The strongest vibrational transitions in molecules are located in the mid-infrared spectral region, between 2 and 12 μ m.

Table 2 Room-temperature absorption line strength in 10^{-21} cm²/(molecule cm) for simple and common molecules in different spectral regions from visible to mid-infrared^a

	Visible/near-infrared	Shortwave mid-infrared	Long-wave mid-infrared
Wavelength	0.7–2.0 μm	2.5–5.0 μm	5.5–12 μm
Wave numbers	5,000–14,500 cm ⁻¹	$2,000-4,000 \text{ cm}^{-1}$	$800-1,800 \text{ cm}^{-1}$
CO ₂	0.3	3000	0.03
СО	0.02	300	0
CH ₄	1	100	50
C_2H_2	10	200	100
H ₂ O	20	200	200
NH ₃	5	10	200
NO	0.04	0.3	20

Annual Review of Analytical Chemistry, Vol. 3, 175-205 (2010)



 \Leftrightarrow Gas monitor

Semiconductor Processing Monitor

Breath Analysis Sensors, Vol. 9, 8230 (2009) Breath Analysis Using Laser Spectroscopic Techniques: Breath $^{\circ}$ **Biomarkers, Spectral Fingerprints, and Detection Limits** Chuji Wang * and Peeyush Sahay Acetaldehyde (CH₃CHO) - alcoholism and lung cancer *Mid-IR Sources* (2~12 micron) Ammonia (NH_3) - renal failure and asthma Carbon dioxide (CO_2) and ¹³C-isotope - Helicobacter and liver malfunction Carbon monoxide (CO) - hypertension and smoking cessation monitor Methane (CH_4) - colonic fermentation and intestinal problems Nitric oxide (NO) - asthma, hypertension, and rhinitis

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Page • 19 [Sanghera and Aggarwal, NRL]

The objective of laser ablation is to remove a definite part of tissue, leaving the surrounding tissues alive. Vessel-carrying tissues cutting : brain surgery requires surface coagulation "thermal damage" in order to reach hemostasis stopping of blood flow. Vessel-free tissues cutting : cosmetology wounds heal better when there is no thermal damage. Soft-tissue cutting: $\lambda = 6.1 \mu m$: the deepest crater and the lowest collateral thermal damage



C Tracking

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Mid-Infrared Lasers 2010 (Market Review and Forecast) Strategies Unlimited says "mid-infrared lasers could be boosted with advancements in several new laser technologies."

Advancements in several laser new technologies are opening new opportunities in the part of the spectrum between telecom lasers and the nascent terahertz range, called the midinfrared. This range is currently dominated by applications in materials processing and medical procedures, but new military and sensing applications will add sizeable and exciting opportunities in the next few years. The new segments will grow 30% per year, compounded annually through 2014.

Page 22 http://compoundsemiconductor.net/csc/news-details.php?cat=news&id=19732386

Thanks For Your Attention!